

SEMICONDUCTOR TECHNICAL DATA

SMBB34

SCHOTTKY BARRIER TYPE DIODE

SWITCHING TYPE POWER SUPPLY APPLICATIONS.

FEATURES

□Low Profile Surface Mount Package.

□Low Power Loss, High Efficiency.

 \Box For Use in Low Voltage, High Frequency inverters, Free

Wheeling, and Polarity Protection Applications.

APPLICATION

☐ Switching Power Supply.

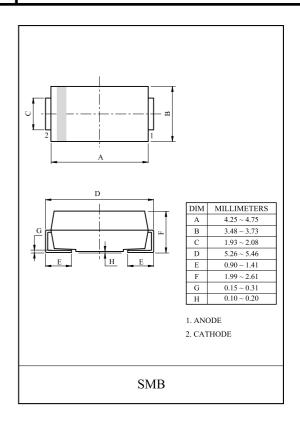
 $\square\,DC/DC$ Converter.

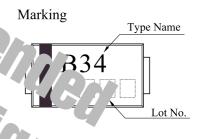
☐ Home Appliances, Office Equipment.

☐ Telecommunication.

MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	J IBOL	RATING	UNIT
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	40	V
Average Output Rectitifed Curre	I _O		A
Peak One Cycle Surge Forwar C re	I		
(Non-Repetitive 60Hz)	I _{FSM}		772
Junction Temperature		-40 ~ 150	7
Storage Temperature Range	• stg	f° ~ 150	$^{\circ}$





ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	V_{FM}	I _{FM} =3.0A	-	-	0.5	V
Repetitive Peak Reverse Current I _{RR}	I	V _{RRM} =Rated, Tj=25 ℃	-	-	0.1	mA
	1RRM	V _{RRM} =Rated, Tj=100 ℃	-	-	10	mA
Total Capacitance	C_{T}	V _R =4V, f=1MHz	-	-	250	pF
Thermal Resistance	R _{th(j-1)}	Junction to lead	-	-	15	°C/W

